

# SAR TEST REPORT

# No. I18Z60544-SEM01

For

**Palm Ventures Group** 

# HSUPA/HSDPA/UMTS Quad Band/GSM Quad Band/LTE 7 Bands mobile phone

Model Name: PVG100

With

Hardware Version: 03

Software Version: 1AT5

FCC ID: 2AOETPVG100

Issued Date: 2018-6-25

R TESTING NVLAP LAB CODE 600118-0

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# **REPORT HISTORY**

	Report Number	Revision	Issue Date	Description
F	I18Z60544-SEM01	Rev.0	2018-6-25	Initial creation of test report



# TABLE OF CONTENT

1 1		5
1.1	TESTING LOCATION	5
1.2	TESTING ENVIRONMENT	5
1.3	PROJECT DATA	5
1.4	SIGNATURE	5
2 3	STATEMENT OF COMPLIANCE	6
3 (	CLIENT INFORMATION	8
3.1	Applicant Information	
3.2	MANUFACTURER INFORMATION	
4 E	EQUIPMENT UNDER TEST (EUT) AND ANCILLARY EQUIPMENT (AE)	9
4.1	About EUT	9
4.2	INTERNAL IDENTIFICATION OF EUT USED DURING THE TEST	9
4.3	INTERNAL IDENTIFICATION OF AE USED DURING THE TEST	9
5 1	TEST METHODOLOGY	10
5.1	APPLICABLE LIMIT REGULATIONS	10
5.2	APPLICABLE MEASUREMENT STANDARDS	10
6 5	SPECIFIC ABSORPTION RATE (SAR)	11
6.1	INTRODUCTION	
6.2	SAR DEFINITION	
7 1	TISSUE SIMULATING LIQUIDS	12
7.1	TARGETS FOR TISSUE SIMULATING LIQUID	
7.2	Dielectric Performance	
8 5	SYSTEM VERIFICATION	18
8.1	System Setup	
8.2	System Verification	
9 N	MEASUREMENT PROCEDURES	20
9.1	TESTS TO BE PERFORMED	20
9.2	GENERAL MEASUREMENT PROCEDURE	
9.3	WCDMA MEASUREMENT PROCEDURES FOR SAR	
9.4	SAR MEASUREMENT FOR LTE	24
9.5	BLUETOOTH & WI-FI MEASUREMENT PROCEDURES FOR SAR	24
9.6	Power Drift	25
10	AREA SCAN BASED 1-G SAR	25
10.1	REQUIREMENT OF KDB	25
10.2	FAST SAR ALGORITHMS	25
11	CONDUCTED OUTPUT POWER	
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11.1	GSM MEASUREMENT RESULT	
11.2	WCDMA MEASUREMENT RESULT	27
11.3	LTE MEASUREMENT RESULT	
11.4	WI-FI AND BT MEASUREMENT RESULT	
12	SIMULTANEOUS TX SAR CONSIDERATIONS	45
12.1	INTRODUCTION	45
12.2	TRANSMIT ANTENNA SEPARATION DISTANCES	
12.3	SAR MEASUREMENT POSITIONS	
12.4	STANDALONE SAR TEST EXCLUSION CONSIDERATIONS	
13	EVALUATION OF SIMULTANEOUS	47
14	SAR TEST RESULT	48
14.1	SAR RESULTS	49
14.2	FULL SAR	67
14.3	WLAN EVALUATION	
15	SAR MEASUREMENT VARIABILITY	71
16	MEASUREMENT UNCERTAINTY	72
16.1	MEASUREMENT UNCERTAINTY FOR NORMAL SAR TESTS (300MHz~3GHz)	72
16.2	MEASUREMENT UNCERTAINTY FOR NORMAL SAR TESTS (3~6GHz)	
16.3	MEASUREMENT UNCERTAINTY FOR FAST SAR TESTS (300MHz~3GHz)	74
16.4	MEASUREMENT UNCERTAINTY FOR FAST SAR TESTS (3~6GHz)	75
17	MAIN TEST INSTRUMENTS	77
ANNE	X A GRAPH RESULTS	78
ANNE	X B SYSTEM VERIFICATION RESULTS	113
ANNE	X C SAR MEASUREMENT SETUP	124
ANNE	X D POSITION OF THE WIRELESS DEVICE IN RELATION TO THE PHA	NTOM 130
ANNE	X E EQUIVALENT MEDIA RECIPES	133
ANNE	X F SYSTEM VALIDATION	134
ANNE	X G PROBE CALIBRATION CERTIFICATE	135
ANNE	X H DIPOLE CALIBRATION CERTIFICATE	146
ANNE		186



# 1 Test Laboratory

## 1.1 Testing Location

Company Name:	CTTL(Shouxiang)	
Address:	No. 51 Shouxiang Science Building, Xueyuan Road, Haidian District,	
	Beijing, P. R. China100191	

## **1.2 Testing Environment**

Temperature:	18°C~25 °C,
Relative humidity:	30%~ 70%
Ground system resistance:	< 0.5 Ω
Ambient noise & Reflection:	< 0.012 W/kg

#### 1.3 Project Data

Project Leader:	Qi Dianyuan
Test Engineer:	Lin Xiaojun
Testing Start Date:	June 12, 2018
Testing End Date:	June 16, 2018

## 1.4 Signature

Lin Xiaojun (Prepared this test report)

Qi Dianyuan (Reviewed this test report)

PB 20th Fi

Lu Bingsong Deputy Director of the laboratory (Approved this test report)



# 2 Statement of Compliance

The maximum results of SAR found during testing for Palm Ventures Group HSUPA/HSDPA/UMTS Quad Band/GSM Quad Band/LTE 7 Bands mobile phone PVG100 is as follows:

Table 2.1: Hignest Reported SAR (1g)				
Exposure Configuration	Technology Band	Highest Reported SAR 1g (W/Kg)	Equipment Class	
	GSM 850	0.78		
	PCS 1900	0.55		
	UMTS FDD 2	0.85		
	UMTS FDD 4	0.61		
	UMTS FDD 5	0.50		
	LTE Band 2 (Low)	0.79		
Head	LTE Band 2	1.26	PCE	
(Separation Distance 0mm)	LTE Band 5	0.59		
	LTE Band 12	0.23		
	LTE Band 13	0.54		
	LTE Band 17	0.29		
	LTE Band 66 (Low)	0.70		
	LTE Band 66	1.08		
	WLAN 2.4 GHz	0.78	DTS	
	GSM 850	0.53		
	PCS 1900	0.42		
	UMTS FDD 2	0.96		
	UMTS FDD 4	0.58		
Dadu	UMTS FDD 5	0.35		
Body (Separation Distance	LTE Band 2	1.02	PCE	
10mm)	LTE Band 5	0.42		
	LTE Band 12	0.24		
	LTE Band 13	0.38		
	LTE Band 17	0.26		
	LTE Band 66	0.89		
	WLAN 2.4 GHz	0.37	DTS	

Table 2.1: Highest Reported SAR (1g)

The SAR values found for the Mobile Phone are below the maximum recommended levels of 1.6 W/Kg as averaged over any 1g tissue according to the ANSI C95.1-1992.

For body worn operation, this device has been tested and meets FCC RF exposure guidelines when used with any accessory that contains no metal and which provides a minimum separation distance of 10 mm between this device and the body of the user. Use of other accessories may not ensure compliance with FCC RF exposure guidelines.

The EUT battery must be fully charged and checked periodically during the test to ascertain uniform power output.

The measurement together with the test system set-up is described in annex C of this test report. A



## No. I18Z60544-SEM01 Page 7 of 186

detailed description of the equipment under test can be found in chapter 4 of this test report. The highest reported SAR value is obtained at the case of **(Table 2.1)**, and the values are: 1.26 **W/kg (1g)**.

	Position	Main antenna	WiFi	Sum
Highest reported SAR value for Head	Right hand, Touch cheek GSM850	0.78	0.78	1.56
Highest reported SAR value for Body	Rear LTE Band2	1.02	0.27	1.29

#### Table 2.2: The sum of reported SAR values for main antenna and WiFi

	Position	Main antenna	BT	Sum
Maximum reported	Left hand, Touch cheek	1.26	0.17	1.43
SAR value for Head	LTE Band2 Normal Power	1.20	0.17	1.43
Maximum reported	Rear	1.02	0.08	1 10
SAR value for Body	LTE Band2	1.02	0.00	1.10

[1] - Estimated SAR for Bluetooth (see the table 13.3)

According to the above tables, the highest sum of reported SAR values is 1.56 **W/kg (1g)**. The detail for simultaneous transmission consideration is described in chapter 13.



# **3** Client Information

## 3.1 Applicant Information

Company Name:	Palm Ventures Group
Address /Post:	461 2nd Street - #C337-San Francisco - CA 94107
Contact Person:	Francois CHAMBON
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## 3.2 Manufacturer Information

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Telephone:	+8618675503761
Fax:	1



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# 4 Equipment Under Test (EUT) and Ancillary Equipment (AE)

4.1 About EUT	
Description:	HSUPA/HSDPA/UMTS Quad Band/GSM Quad Band/LTE 7 Bands
	mobile phone
Model name:	PVG100
Operating mode(s):	GSM 850/900/1800/1900 WCDMA850/1700/1900/2100
operating mode(s).	LTE B2/4/5/12/13/17/66, BT, WLAN
	825 – 848.8 MHz (GSM 850)
	1850.2 – 1910 MHz (GSM 1900)
	826.4–846.6 MHz (WCDMA 850 Band V)
	1712.4 – 1752.6 MHz (WCDMA 1700 Band IV)
	1852.4–1907.6 MHz (WCDMA1900 Band II)
Tested Tx Frequency:	1860 – 1900 MHz (LTE Band 2)
	824.7 – 848.3 MHz (LTE Band 5)
	699.7 – 715.3 MHz (LTE Band 12)
	779.5 –784.5 MHz (LTE Band 13)
	706.5 – 713.5MHz(LTE Band 17)
	1710.7 –1779.3 MHz (LTE Band 66)
	2412 – 2462 MHz (Wi-Fi 2.4G)
GPRS/EGPRS Multislot Class:	12
GPRS capability Class:	
Test device Production information:	Production unit
Device type:	Portable device
Antenna type:	Integrated antenna
Hotspot mode:	Support
Product dimension	Long 96.6mm ;Wide 50.6mm ; Overall Diagonal 109.05mm

#### 4.2 Internal Identification of EUT used during the test

		U	
EUT1	015150000001756	03	1AT5
EUT2	015150000001657	03	1AT5
EUT3	015150000001699	03	1AT5

\*EUT ID: is used to identify the test sample in the lab internally.

Note: It is performed to test SAR with the EUT1&2and conducted power with the EUT3.

#### 4.3 Internal Identification of AE used during the test

AE ID	Description	Model	SN	Manufactor
AE1	Battery	CAC0770000C1	0	BYD

\*AE ID: is used to identify the test sample in the lab internally.



# 5 TEST METHODOLOGY

#### 5.1 Applicable Limit Regulations

**ANSI C95.1–1992:** IEEE Standard for Safety Levels with Respect to Human Exposure to Radio Frequency Electromagnetic Fields, 3 kHz to 300 GHz.

It specifies the maximum exposure limit of **1.6 W/kg** as averaged over any 1 gram of tissue for portable devices being used within 20 cm of the user in the uncontrolled environment.

#### 5.2 Applicable Measurement Standards

**IEEE 1528–2013:** Recommended Practice for Determining the Peak Spatial-Average Specific Absorption Rate (SAR) in the Human Head from Wireless Communications Devices: Measurement Techniques.

**KDB447498 D01 General RF Exposure Guidance v06:** Mobile and Portable Devices RF Exposure Procedures and Equipment Authorization Policies.

KDB648474 D04 Handset SAR v01r03: SAR Evaluation Considerations for Wireless Handsets.

**KDB941225 D01 SAR test for 3G devices v03r01:** SAR Measurement Procedures for 3G Devices

KDB941225 D05 SAR for LTE Devices v02r05: SAR Evaluation Considerations for LTE Devices

KDB248227 D01 802.11 Wi-Fi SAR v02r02: SAR GUIDANCE FOR IEEE 802.11 (Wi-Fi) TRANSMITTERS

**KDB865664 D01SAR measurement 100 MHz to 6 GHz v01r04:** SAR Measurement Requirements for 100 MHz to 6 GHz.

**KDB865664 D02 RF Exposure Reporting v01r02:** RF Exposure Compliance Reporting and Documentation Considerations



# 6 Specific Absorption Rate (SAR)

#### 6.1 Introduction

SAR is related to the rate at which energy is absorbed per unit mass in an object exposed to a radio field. The SAR distribution in a biological body is complicated and is usually carried out by experimental techniques or numerical modeling. The standard recommends limits for two tiers of groups, occupational/controlled and general population/uncontrolled, based on a person's awareness and ability to exercise control over his or her exposure. In general, occupational/controlled exposure limits are higher than the limits for general population/uncontrolled.

#### 6.2 SAR Definition

The SAR definition is the time derivative (rate) of the incremental energy (dW) absorbed by (dissipated in) an incremental mass (dm) contained in a volume element (dv) of a given density ( $\rho$ ). The equation description is as below:

$$SAR = \frac{d}{dt} \left(\frac{dW}{dm}\right) = \frac{d}{dt} \left(\frac{dW}{\rho dv}\right)$$

SAR is expressed in units of Watts per kilogram (W/kg) SAR measurement can be either related to the temperature elevation in tissue by

$$SAR = c(\frac{\delta T}{\delta t})$$

Where: C is the specific head capacity,  $\delta T$  is the temperature rise and  $\delta t$  is the exposure duration, or related to the electrical field in the tissue by

$$SAR = \frac{\sigma |E|^2}{\rho}$$

Where:  $\sigma$  is the conductivity of the tissue,  $\rho$  is the mass density of tissue and E is the RMS electrical field strength.

However for evaluating SAR of low power transmitter, electrical field measurement is typically applied.



# 7 Tissue Simulating Liquids

## 7.1 Targets for tissue simulating liquid

Table 7.1: Targets for tissue simulating liquid

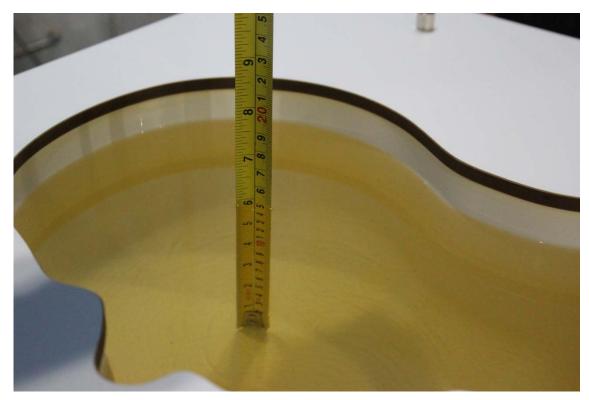
Frequency(MHz)	Liquid Type	Conductivity(σ)	± 5% Range	Permittivity(ε)	± 5% Range
750	Head	0.89	0.85~0.93	41.94	39.8~44.0
750	Body	0.96	0.91~1.01	55.5	52.7~58.3
835	Head	0.90	0.86~0.95	41.5	39.4~43.6
835	Body	0.97	0.92~1.02	55.2	52.4~58.0
1750	Head	1.37	1.30~1.44	40.08	38.1~42.1
1750	Body	1.49	1.42~1.56	53.4	50.7~56.1
1900	Head	1.40	1.33~1.47	40.0	38.0~42.0
1900	Body	1.52	1.44~1.60	53.3	50.6~56.0
2450	Head	1.80	1.71~1.89	39.2	37.2~41.2
2450	Body	1.95	1.85~2.05	52.7	50.1~55.3
2600	Head	1.96	1.86~2.06	39.01	37.1~41.0
2600	Body	2.16	2.05~2.27	52.5	49.9~55.1

## 7.2 Dielectric Performance

#### Table 7.2: Dielectric Performance of Tissue Simulating Liquid

Measurement Date yyyy/mm/dd	Frequency	Туре	Permittivity ε	Drift (%)	Conductivity σ (S/m)	Drift (%)
2018/6/12	750 MHz	Head	41.64	-0.72	0.898	0.90
2010/0/12		Body	56.28	1.41	0.972	1.25
2018/6/13	835 MHz	Head	41.79	0.70	0.896	-0.44
2010/0/13		Body	54.61	-1.07	0.962	-0.82
2018/6/14	1750 MHz	Head	39.8	-0.70	1.397	1.97
2010/0/14		Body	53.85	0.84	1.461	-1.95
2018/6/15	1900 MHz	Head	39.46	-1.35	1.389	-0.79
2010/0/13		Body	54.11	1.52	1.529	0.59
2019/6/16	2450 MHz	Head	38.71	-1.25	1.814	0.78
2018/6/16		Body	53.67	1.84	1.959	0.46





Picture 7-1 Liquid depth in the Head Phantom (750 MHz)



Picture 7-2 Liquid depth in the Flat Phantom (750 MHz)





Picture 7-3 Liquid depth in the Head Phantom (835MHz)

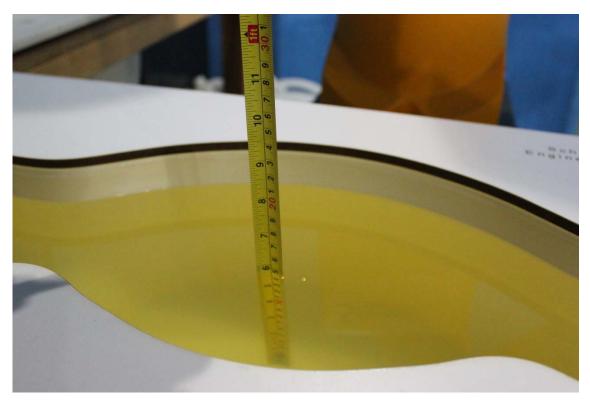


Picture 7-4 Liquid depth in the Flat Phantom (835MHz)





Picture 7-5 Liquid depth in the Head Phantom (1750 MHz)



Picture 7-6 Liquid depth in the Flat Phantom (1750MHz)





Picture 7-7 Liquid depth in the Head Phantom (1900 MHz)

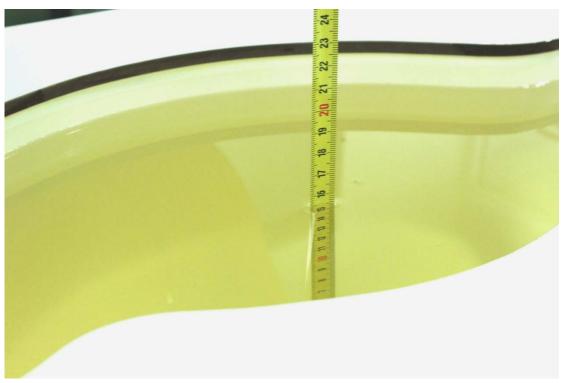


Picture 7-8 Liquid depth in the Flat Phantom (1900MHz)





Picture 7-9 Liquid depth in the Head Phantom (2450MHz)



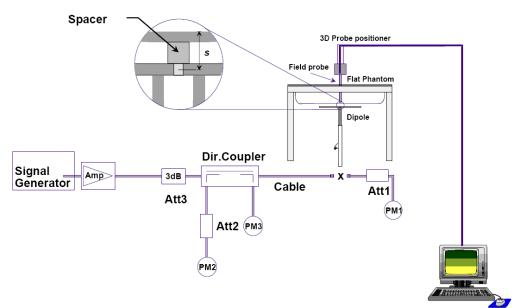
Picture 7-10 Liquid depth in the Flat Phantom (2450MHz)



# 8 System verification

#### 8.1 System Setup

In the simplified setup for system evaluation, the DUT is replaced by a calibrated dipole and the power source is replaced by a continuous wave that comes from a signal generator. The calibrated dipole must be placed beneath the flat phantom section of the SAM twin phantom with the correct distance holder. The distance holder should touch the phantom surface with a light pressure at the reference marking and be oriented parallel to the long side of the phantom. The equipment setup is shown below:



Picture 8.1 System Setup for System Evaluation



Picture 8.2 Photo of Dipole Setup



## 8.2 System Verification

SAR system verification is required to confirm measurement accuracy, according to the tissue dielectric media, probe calibration points and other system operating parameters required for measuring the SAR of a test device. The system verification must be performed for each frequency band and within the valid range of each probe calibration point required for testing the device.

The system verification results are required that the area scan estimated 1-g SAR is within 3% of the zoom scan 1-g SAR. The details are presented in annex B.

Measurement Date	ate		Target value (W/kg)		ed value kg)	Deviation					
(yyyy-mm- dd)	Frequency	10 g Average	1 g Average	10 g Average	1 g Average	10 g Average	1 g Average				
2018/6/12	750 MHz	5.42	8.32	5.36	8.44	-1.11%	1.44%				
2018/6/13	835 MHz	6.06	9.37	6.16	9.44	1.65%	0.75%				
2018/6/14	1750 MHz	19.4	36.7	19.32	36.96	-0.41%	0.71%				
2018/6/15	1900 MHz	21.0	40.0	21.24	40.24	1.14%	0.60%				
2018/6/16	2450 MHz	24.7	52.2	24.52	52.44	-0.73%	0.46%				

Table 8.1: System Verification of Head

Table 8.2: System Verification of Body

Measurement Date		Target value (W/kg)			ed value kg)	Deviation		
(yyyy-mm-	Frequency	10 g	1 g	10 g	1 g	10 g	1 g	
dd)		Average	Average	Average	Average	Average	Average	
2018/6/12	750 MHz	5.68	8.66	5.6	8.56	-1.41%	-1.15%	
2018/6/13	835 MHz	6.12	9.41	6.2	9.32	1.31%	-0.96%	
2018/6/14	1750 MHz	19.8	37.1	20	37.52	1.01%	1.13%	
2018/6/15	1900 MHz	21.5	40.5	21.56	41.28	0.28%	1.93%	
2018/6/16	2450 MHz	23.8	50.4	23.6	51.12	-0.84%	1.43%	



# 9 Measurement Procedures

## 9.1 Tests to be performed

In order to determine the highest value of the peak spatial-average SAR of a handset, all device positions, configurations and operational modes shall be tested for each frequency band according to steps 1 to 3 below. A flowchart of the test process is shown in picture 9.1.

Step 1: The tests described in 9.2 shall be performed at the channel that is closest to the center of

the transmit frequency band ( $f_c$ ) for:

a) all device positions (cheek and tilt, for both left and right sides of the SAM phantom, as described in annex D),

b) all configurations for each device position in a), e.g., antenna extended and retracted, and

c) all operational modes, e.g., analogue and digital, for each device position in a) and configuration in b) in each frequency band.

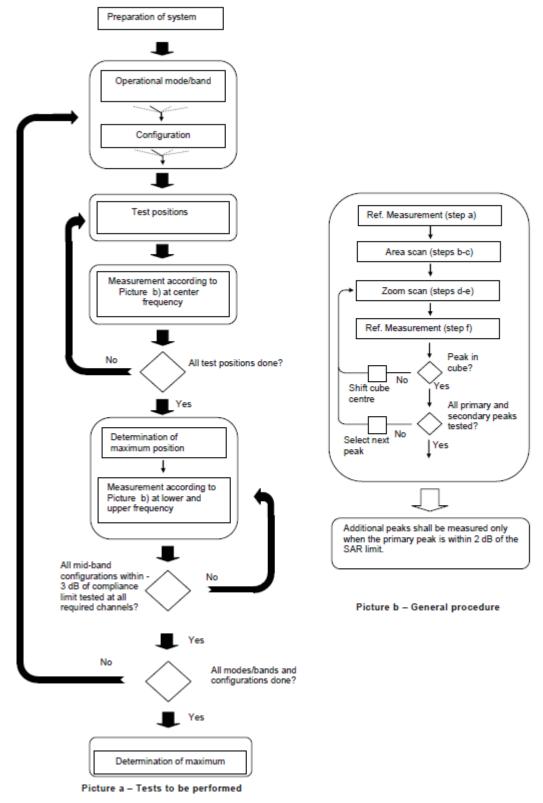
If more than three frequencies need to be tested according to 11.1 (i.e.,  $N_c$  > 3), then all

frequencies, configurations and modes shall be tested for all of the above test conditions.

**Step 2**: For the condition providing highest peak spatial-average SAR determined in Step 1, perform all tests described in 9.2 at all other test frequencies, i.e., lowest and highest frequencies. In addition, for all other conditions (device position, configuration and operational mode) where the peak spatial-average SAR value determined in Step 1 is within 3 dB of the applicable SAR limit, it is recommended that all other test frequencies shall be tested as well.

**Step 3**: Examine all data to determine the highest value of the peak spatial-average SAR found in Steps 1 to 2.





Picture 9.1 Block diagram of the tests to be performed



#### 9.2 General Measurement Procedure

The area and zoom scan resolutions specified in the table below must be applied to the SAR measurements and fully documented in SAR reports to qualify for TCB approval. Probe boundary effect error compensation is required for measurements with the probe tip closer than half a probe tip diameter to the phantom surface. Both the probe tip diameter and sensor offset distance must satisfy measurement protocols; to ensure probe boundary effect errors are minimized and the higher fields closest to the phantom surface can be correctly measured and extrapolated to the phantom surface for computing 1-g SAR. Tolerances of the post-processing algorithms must be verified by the test laboratory for the scan resolutions used in the SAR measurements, according to the reference distribution functions specified in IEEE Std 1528-2013. The results should be documented as part of the system validation records and may be requested to support test results when all the measurement parameters in the following table are not satisfied.

			$\leq$ 3 GHz	> 3 GHz		
Maximum distance from (geometric center of pro			$5 \pm 1 \text{ mm}$	$\frac{1}{2} \cdot \delta \cdot \ln(2) \pm 0.5 \text{ mm}$		
Maximum probe angle f normal at the measurem			30°±1°	20° ± 1°		
			$\leq 2 \text{ GHz:} \leq 15 \text{ mm}$ 2 – 3 GHz: $\leq 12 \text{ mm}$	$\begin{array}{l} 3-4 \ \mathrm{GHz:} \leq 12 \ \mathrm{mm} \\ 4-6 \ \mathrm{GHz:} \leq 10 \ \mathrm{mm} \end{array}$		
Maximum area scan spa	itial resoluti	on: Δx <sub>Ares</sub> , Δy <sub>Area</sub>	When the x or y dimension of t measurement plane orientation measurement resolution must b dimension of the test device with point on the test device.	, is smaller than the above, the $\leq$ the corresponding x or y		
Maximum zoom scan sp	oatial resolu	tion: Δx <sub>Zoom</sub> , Δy <sub>Zoom</sub>	$\leq 2 \text{ GHz} \leq 8 \text{ mm}$ 2 - 3 GHz: $\leq 5 \text{ mm}^{*}$	3 – 4 GHz: ≤ 5 mm <sup>4</sup> 4 – 6 GHz: ≤ 4 mm <sup>4</sup>		
	uniform g	rrid: ∆z <sub>Zoom</sub> (n)	≤ 5 mm	$\begin{array}{l} 3-4 \ \text{GHz:} \leq 4 \ \text{mm} \\ 4-5 \ \text{GHz:} \leq 3 \ \text{mm} \\ 5-6 \ \text{GHz:} \leq 2 \ \text{mm} \end{array}$		
Maximum zoom scan spatial resolution, normal to phantom surface	graded	$\Delta z_{Zoom}(1)$ : between 1 <sup>st</sup> two points closest to phantom surface	≤ 4 mm	$3 - 4 \text{ GHz} \le 3 \text{ mm}$ $4 - 5 \text{ GHz} \le 2.5 \text{ mm}$ $5 - 6 \text{ GHz} \le 2 \text{ mm}$		
	grid $\Delta z_{Zoom}(n>1)$ : between subsequent points		$\leq 1.5 \cdot \Delta z_{Zoom}(n-1)$			
Minimum zoom scan volume	x, y, z	1	≥ 30 mm	$3 - 4 \text{ GHz}: \ge 28 \text{ mm}$ $4 - 5 \text{ GHz}: \ge 25 \text{ mm}$ $5 - 6 \text{ GHz}: \ge 22 \text{ mm}$		

\* When zoom scan is required and the <u>reported</u> SAR from the area scan based *1-g SAR estimation* procedures of KDB 447498 is ≤ 1.4 W/kg, ≤ 8 mm, ≤ 7 mm and ≤ 5 mm zoom scan resolution may be applied, respectively, for 2 GHz to 3 GHz, 3 GHz to 4 GHz and 4 GHz to 6 GHz.



## 9.3 WCDMA Measurement Procedures for SAR

The following procedures are applicable to WCDMA handsets operating under 3GPP Release99, Release 5 and Release 6. The default test configuration is to measure SAR with an established radio link between the DUT and a communication test set using a 12.2kbps RMC (reference measurement channel) configured in Test Loop Mode 1. SAR is selectively confirmed for other physical channel configurations (DPCCH & DPDCH<sub>n</sub>), HSDPA and HSPA (HSUPA/HSDPA) modes according to output power, exposure conditions and device operating capabilities. Both uplink and downlink should be configured with the same RMC or AMR, when required. SAR for Release 5 HSDPA and Release 6 HSPA are measured using the applicable FRC (fixed reference channel) and E-DCH reference channel configurations. Maximum output power is verified according to applicable versions of 3GPP TS 34.121 and SAR must be measured according to these maximum output conditions. When Maximum Power Reduction (MPR) is not implemented according to Cubic Metric (CM) requirements for Release 6 HSPA, the following procedures do not apply.

Sub-test	$eta_c$	$eta_{d}$	$eta_d$ (SF)	$eta_c / eta_d$	$eta_{\scriptscriptstyle hs}$	CM/dB
1	2/15	15/15	64	2/15	4/15	0.0
2	12/15	15/15	64	12/15	24/25	1.0
3	15/15	8/15	64	15/8	30/15	1.5
4	15/15	4/15	64	15/4	30/15	1.5

#### For Release 5 HSDPA Data Devices:

#### For Release 6 HSPA Data Devices

Sub- test	$eta_{c}$	$eta_{d}$	β <sub>d</sub> (SF)	$eta_c$ / $eta_d$	$eta_{\scriptscriptstyle hs}$	$eta_{\scriptscriptstyle ec}$	$eta_{_{ed}}$	$eta_{ed}$	$eta_{ed}$	CM (dB)	MPR (dB)	AG Index	E- TFCI
1	11/15	15/15	64	11/15	22/15	209/225	1039/225	4	1	1.5	1.5	20	75
2	6/15	15/15	64	6/15	12/15	12/15	12/15	4	1	1.5	1.5	12	67
3	15/15	9/15	64	15/9	30/15	30/15	$eta_{ed1}^{}{}_{:47/15}^{}$ $eta_{ed2}^{}{}_{:47/15}^{}$	4	2	1.5	1.5	15	92
4	2/15	15/15	64	2/15	4/15	4/15	56/75	4	1	1.5	1.5	17	71
5	15/15	15/15	64	15/15	24/15	30/15	134/15	4	1	1.5	1.5	21	81

#### Rel.8 DC-HSDPA (Cat 24)

SAR test exclusion for Rel.8 DC-HSDPA must satisfy the SAR test exclusion requirements of Rel.5 HSDPA. SAR test exclusion for DC-HSDPA devices is determined by power measurements according to the H-Set 12, Fixed Reference Channel (FRC) configuration in Table C.8.1.12 of 3GPP TS 34.121-1. A primary and a secondary serving HS-DSCH Cell are required to perform the power measurement and for the results to qualify for SAR test exclusion.



## 9.4 SAR Measurement for LTE

SAR tests for LTE are performed with a base station simulator, Rohde & Rchwarz CMW500. Closed loop power control was used so the UE transmits with maximum output power during SAR testing. All powers were measured with the CMW 500.

It is performed for conducted power and SAR based on the KDB941225 D05.

SAR is evaluated separately according to the following procedures for the different test positions in each exposure condition – head, body, body-worn accessories and other use conditions. The procedures in the following subsections are applied separately to test each LTE frequency band.

1) QPSK with 1 RB allocation

Start with the largest channel bandwidth and measure SAR for QPSK with 1 RB allocation, using the RB offset and required test channel combination with the highest maximum output power among RB offsets at the upper edge, middle and lower edge of each required test channel. When the reported SAR is  $\leq 0.8$  W/kg, testing of the remaining RB offset configurations and required test channels is not required for 1 RB allocation; otherwise, SAR is required for the remaining required test channels and only for the RB offset configuration with the highest output power for that channel. When the reported SAR of a required test channel is > 1.45 W/kg, SAR is required for all three RB offset configurations for that required test channel.

- QPSK with 50% RB allocation
  The procedures required for 1 RB allocation in 1) are applied to measure the SAR for QPSK with 50% RB allocation.
- 3) QPSK with 100% RB allocation

For QPSK with 100% RB allocation, SAR is not required when the highest maximum output power for 100 % RB allocation is less than the highest maximum output power in 50% and 1 RB allocations and the highest reported SAR for 1 RB and 50% RB allocation in 1) and 2) are  $\leq$  0.8 W/kg. Otherwise, SAR is measured for the highest output power channel; and if the reported SAR is > 1.45 W/kg, the remaining required test channels must also be tested.

#### 9.5 Bluetooth & Wi-Fi Measurement Procedures for SAR

Normal network operating configurations are not suitable for measuring the SAR of 802.11 transmitters in general. Unpredictable fluctuations in network traffic and antenna diversity conditions can introduce undesirable variations in SAR results. The SAR for these devices should be measured using chipset based test mode software to ensure that the results are consistent and reliable.

Chipset based test mode software is hardware dependent and generally varies among manufacturers. The device operating parameters established in a test mode for SAR measurements must be identical to those programmed in production units, including output power levels, amplifier gain settings and other RF performance tuning parameters. The test frequencies should correspond to actual channel frequencies defined for domestic use. SAR for devices with switched diversity should be measured with only one antenna transmitting at a time during each SAR measurement, according to a fixed modulation and data rate. The same data pattern should be used for all measurements.



## 9.6 Power Drift

To control the output power stability during the SAR test, DASY4 system calculates the power drift by measuring the E-field at the same location at the beginning and at the end of the measurement for each test position. These drift values can be found in section 14 labeled as: (Power Drift [dB]). This ensures that the power drift during one measurement is within 5%.

# 10 Area Scan Based 1-g SAR

## 10.1 Requirement of KDB

According to the KDB447498 D01 v05, when the implementation is based the specific polynomial fit

algorithm as presented at the 29th Bioelectromagnetics Society meeting (2007) and the estimated 1-g SAR is  $\leq$  1.2 W/kg, a zoom scan measurement is not required provided it is also not needed for any other purpose; for example, if the peak SAR location required for simultaneous transmission SAR test exclusion can be determined accurately by the SAR system or manually to discriminate between distinctive peaks and scattered noisy SAR distributions from area scans.

There must not be any warning or alert messages due to various measurement concerns identified by the SAR system; for example, noise in measurements, peaks too close to scan boundary, peaks are too sharp, spatial resolution and uncertainty issues etc. The SAR system verification must also demonstrate that the area scan estimated 1-g SAR is within 3% of the zoom scan 1-g SAR (See Annex B). When all the SAR results for each exposure condition in a frequency band and wireless mode are based on estimated 1-g SAR, the 1-g SAR for the highest SAR configuration must be determined by a zoom scan.

## 10.2 Fast SAR Algorithms

The approach is based on the area scan measurement applying a frequency dependent attenuation parameter. This attenuation parameter was empirically determined by analyzing a large number of phones. The MOTOROLA FAST SAR was developed and validated by the MOTOROLA Research Group in Ft. Lauderdale.

In the initial study, an approximation algorithm based on Linear fit was developed. The accuracy of the algorithm has been demonstrated across a broad frequency range (136-2450 MHz) and for both 1- and 10-g averaged SAR using a sample of 264 SAR measurements from 55 wireless handsets. For the sample size studied, the root-mean-squared errors of the algorithm are 1.2% and 5.8% for 1- and 10-g averaged SAR, respectively. The paper describing the algorithm in detail is expected to be published in August 2004 within the Special Issue of Transactions on MTT.

In the second step, the same research group optimized the fitting algorithm to an Polynomial fit whereby the frequency validity was extended to cover the range 30-6000MHz. Details of this study can be found in the BEMS 2007 Proceedings.

Both algorithms are implemented in DASY software.



# **11 Conducted Output Power**

#### **11.1 GSM Measurement result**

During the process of testing, the EUT was controlled via Agilent Digital Radio Communication tester (E5515C) to ensure the maximum power transmission and proper modulation. This result contains conducted output power for the EUT. In all cases, the measured peak output power should be greater and within 5% than EMI measurement.

			GSM85	50 #1				
		Meas	ured Power	(dBm)		Frame B	urst Power	(dBm)
Config	Tune-up	CH251	CH190	CH128	Caculation	CH251	CH190	CH128
comg	Tune-up	848.8 MHz	836.6 MHz	824.2 MHz		848.8 MHz	836.6 MHz	824.2 MHz
GSM Speech	33.50	31.93	31.88	32.11	-9.03	22.90	22.85	23.08
GPRS 1 Txslot	33.50	32.49	32.76	32.70	-9.03	23.46	23.73	23.67
GPRS 2 Txslots	31.00	30.12	30.25	30.34	-6.02	24.10	24.23	24.32
GPRS 3 Txslots	29.00	28.54	28.58	28.67	-4.26	24.28	24.32	24.41
GPRS 4 Txslots	27.50	27.27	27.22	27.39	-3.01	24.26	24.21	24.38
EGPRS GMSK 1 Txslot	33.50	32.54	32.83	32.70	-9.03	23.51	23.80	23.67
EGPRS GMSK 2 Txslots	31.00	30.16	30.31	30.32	-6.02	24.14	24.29	24.30
EGPRS GMSK 3 Txslots	29.00	28.58	28.64	28.73	-4.26	24.32	24.38	24.47
EGPRS GMSK 4 Txslots	27.50	27.32	27.31	27.46	-3.01	24.31	24.30	24.45
EGPRS 8PSK 1 Txslot	26.00	25.75	25.92	25.83	-9.03	16.72	16.89	16.80
EGPRS 8PSK 2 Txslots	25.50	25.37	25.46	25.45	-6.02	19.35	19.44	19.43
EGPRS 8PSK 3 Txslots	24.50	24.27	24.46	24.36	-4.26	20.01	20.20	20.10
EGPRS 8PSK 4 Txslots	22.50	22.24	22.37	22.38	-3.01	19.23	19.36	19.37

#### Table 11-1 GSM850 #1

#### Table 11-2 PCS1900 #1

			PCS19	00 #1					
		Measu	ured Power	(dBm)		Frame B	urst Power	(dBm)	
Config	Tune-up	CH810 1909.8 MHz	CH661 1880 MHz	CH512 1850.2 MHz	Caculation	CH810 1909.8 MHz	CH661 1880 MHz	CH512 1850.2 MHz	
GSM Speech	30.50	29.92	30.21	30.08	-9.03	20.89	21.18	21.05	
GPRS 1 Txslot	30.50	29.96	30.23	30.02	-9.03	20.93	21.20	20.99	
GPRS 2 Txslots	28.50	27.80	28.13	28.22	-6.02	21.78	22.11	22.20	
GPRS 3 Txslots	26.50	25.78	25.89	26.00	-4.26	21.52	21.63	21.74	
GPRS 4 Txslots	25.50	24.71	25.01	25.13	-3.01	21.70	22.00	22.12	
EGPRS GMSK 1 Txslot	30.50	29.97	30.21	30.06	-9.03	20.94	21.18	21.03	
EGPRS GMSK 2 Txslots	28.50	27.78	28.11	28.28	-6.02	21.76	22.09	22.26	
EGPRS GMSK 3 Txslots	26.50	25.69	25.94	25.98	-4.26	21.43	21.68	21.72	
EGPRS GMSK 4 Txslots	25.50	24.93	25.08	25.10	-3.01	21.92	22.07	22.09	
EGPRS 8PSK 1 Txslot	26.50	25.98	25.70	25.77	-9.03	16.95	16.67	16.74	
EGPRS 8PSK 2 Txslots	26.00	25.14	25.41	25.58	-6.02	19.12	19.39	19.56	
EGPRS 8PSK 3 Txslots	24.50	23.29	23.84	23.99	-4.26	19.03	19.58	19.73	
EGPRS 8PSK 4 Txslots	23.00	22.47	22.22	22.15	-3.01	19.46	19.21	19.14	

#### NOTES:

**Division Factors** 

To average the power, the division factor is as follows:

1TX-slot = 1 transmit time slot out of 8 time slots=> conducted power divided by (8/1) => -9.03dB

2TX-slots = 2 transmit time slots out of 8 time slots=> conducted power divided by (8/2) => -6.02dB

3TX-slots = 3 transmit time slots out of 8 time slots=> conducted power divided by (8/3) => -4.26dB

4TX-slots = 4 transmit time slots out of 8 time slots=> conducted power divided by (8/4) => -3.01dB

# According to the conducted power as above, the body measurements are performed with 3Txslots for 850MHz GPRS, 2Txslots for 1900MHz EGPRS.



#### **11.2 WCDMA Measurement result**

#### Table 11-3 WCDMA1900-BII #1

WCDMA1900-BII #1									
			Meas	ured Power	(dBm)				
Itom		Tung un	CH9538	CH9400	CH9262				
Item		Tune-up	1907.6 MHz	1880 MHz	1852.4 MHz				
WCDMA	RMC	22.30	20.74	20.69	20.82				
	subtest1	21.00	20.88	20.76	20.71				
	subtest2	21.00	20.96	20.86	20.78				
HSUPA	subtest3	21.00	20.81	20.83	20.84				
	subtest4	21.00	20.92	20.81	20.85				
	subtest5	21.00	20.93	20.91	20.79				
HSPA+	١	١	١	١	١				
	subtest1	22.30	21.25	21.10	21.09				
DC-HSDPA	subtest2	22.30	21.17	21.12	21.01				
DC-NODPA	subtest3	22.30	21.24	21.16	21.03				
	subtest4	22.30	21.22	21.18	21.02				

#### Table 11-4 WCDMA1700-BIV #1

WCDMA1700-BIV #1									
			Meas	ured Power	(dBm)				
ltem		Tune-up	CH1513	CH1412	CH1312				
		i une-up	1752.6 MHz	1732.4 MHz	1712.4 MHz				
WCDMA	RMC	23.00	22.48	22.58	22.67				
	subtest1	22.00	20.98	21.07	21.05				
	subtest2	22.00	20.93	21.09	21.14				
HSUPA	subtest3	22.00	20.96	21.13	21.10				
	subtest4	22.00	20.93	21.13	21.17				
	subtest5	22.00	20.99	21.05	21.06				
HSPA+	١	١	\	١	\				
	subtest1	22.00	20.97	21.05	21.20				
DC-HSDPA	subtest2	22.00	20.95	21.06	21.23				
DC-HSDFA	subtest3	22.00	20.96	21.09	21.19				
	subtest4	22.00	20.94	21.04	21.17				

#### Table 11-5 WCDMA850-BV #1

WCDMA850-BV #1									
			Meas	ured Power	(dBm)				
ltem		Tune-up		CH4182	CH4132				
item	item		846.6 MHz	835.4 MHz	826.4 MHz				
WCDMA	RMC	23.00	22.48	22.58	22.67				
	subtest1	22.00	21.43	21.40	21.54				
	subtest2	22.00	20.95	20.93	21.14				
HSUPA	subtest3	22.00	21.57	21.43	21.57				
	subtest4	22.00	21.44	21.42	21.56				
	subtest5	21.00	20.56	20.36	20.54				
HSPA+	١	١	\	١	١				
	subtest1	22.00	21.02	20.99	21.16				
DC-HSDPA	subtest2	22.00	20.99	20.97	21.13				
DC-HODFA	subtest3	22.00	21.04	20.92	21.19				
	subtest4	22.00	21.01	20.99	21.11				



## **11.3 LTE Measurement result**

		LTE	1900-FDD2 #	#1				
SN				Measured Power (dBm) & MPR				
BandWidth	RB No./Start	Channel	Tune-up	QF Measured	PSK	16G Measured	AM	
Bandwidth	RB N0./Start	Channel	rune-up	Power	MPR	Power	MPR	
		19193	21	20.69	0	20.49	0	
	1H	18900	21	20.91	0	20.76	0	
		18607	21	20.89	0	20.31	0	
		19193	21	20.76	0	20.46	0	
	1M	18900	21	20.68	0	20.90	0	
		18607	21	20.31	0	20.22	0	
	1L	19193 18900	21 21	20.20 20.27	0	20.39 20.19	0	
		18607	21	20.27	0	20.29	0	
		19193	21	20.59	0	20.60	0	
1.4MHz	ЗН	18900	21	20.39	0	20.04	0	
		18607	21	20.58	0	20.33	0	
		19193	21	20.55	0	20.72	0	
	3M	18900	21	20.56	0	20.09	0	
		18607	21	20.56	0	20.39	0	
	3L	19193 18900	21 21	20.35 20.48	0	20.70 20.44	0	
	52	18607	21	20.48	0	20.44	0	
		19193	21	20.46	0	20.68	0	
	6	18900	21	20.41	0	20.74	0	
		18607	21	20.42	0	20.19	0	
		19185	21	20.30	0	20.22	0	
	1H	18900	21	20.32	0	20.34	0	
		18615	21	20.99	0	20.32	0	
	1M	19185 18900	21 21	20.38 20.54	0	20.71 20.37	0	
	1111	18615	21	20.54	0	20.37	0	
		19185	21	20.45	0	20.11	0	
	1L	18900	21	20.47	0	20.18	0	
		18615	21	20.44	0	20.24	0	
		19185	21	20.56	0	20.34	0	
3MHz 8H	8H	18900	21	20.46	0	20.34	0	
		18615	21	20.62	0	20.61	0	
	014	19185	21	20.47	0	20.50	0	
	8M	18900 18615	21 21	20.33 20.47	0	20.41 20.65	0	
		19185	21	20.50	0	20.57	0	
	8L	18900	21	20.38	0	20.44	0	
		18615	21	20.47	0	20.68	0	
		19185	21	20.43	0	20.61	0	
	15	18900	21	20.31	0	20.22	0	
		18615	21	20.47	0	20.49	0	
		19175	21	20.37	0	20.11	0	
	1H	19175	21	20.37	0	20.11	0	
		18625	21	20.59	0	20.37	0	
		19175	21	20.91	0	20.37	0	
	1M	18900	21	20.52	0	20.78	0	
		18625	21	20.96	0	20.35	0	
		19175	21	20.43	0	20.07	0	
	1L	18900	21	20.28	0	20.03	0	
		18625	21	20.51	0	20.07	0	
5MHz	12H	19175 18900	21 21	20.49 20.40	0	20.40 20.41	0	
5441 IZ	1211	18625	21	20.40	0	20.41	0	
		19175	21	20.47	0	20.35	0	
	12M	18900	21	20.47	0	20.35	0	
		18625	21	20.52	0	20.68	0	
		19175	21	20.35	0	20.36	0	
	12L	18900	21	20.41	0	20.41	0	
		18625	21	20.52	0	20.43	0	
	25	19175	21	20.40	0	20.70	0	
	25	18900 18625	21 21	20.39 20.46	0	20.55 20.52	0	
		.0020	21	20.40		20.02	~	

#### Table 11-6 LTE1900-FDD2 #1 Low Power

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# No. I18Z60544-SEM01 Page 29 of 186



		19150	21	20.30	0	20.15	0
	1H	18900	21		0		0
		18650		20.12		20.26	
			21	20.60	0	20.10	0
		19150	21	20.51	0	20.16	0
	1M	18900	21	20.65	0	20.57	0
		18650	21	20.88	0	20.39	0
		19150	21	20.42	0	20.06	0
	1L	18900	21	20.27	0	19.94	0
		18650	21	20.61	0	20.31	0
		19150	21	20.55	0	20.46	0
	0511	18900					
10MHz	25H		21	20.58	0	20.42	0
		18650	21	20.66	0	20.48	0
		19150	21	20.71	0	20.39	0
	25M	18900	21	20.64	0	20.62	0
		18650	21	20.48	0	20.58	0
		19150	21	20.47	0	20.45	0
	25L	18900	21	20.52	0	20.42	0
	201				0		0
		18650	21	20.53		20.58	
	i transfer a	19150	21	20.51	0	20.32	0
	50	18900	21	20.48	0	20.39	0
		18650	21	20.50	0	20.44	0
		19125	21	20.50	0	20.20	0
	1H	18900	21	20.13	0	20.10	0
					0		0
		18675	21	20.67		20.24	
		19125	21	20.64	0	20.95	0
	1M	18900	21	20.72	0	20.20	0
		18675	21	20.65	0	20.25	0
	1L	19125	21	20.75	0	20.80	0
		18900	21	20.37	0	20.35	0
		18675	21	20.22	0	20.26	0
		19125	21	20.36	0	20.33	0
15MHz	36H						
IDIVIHZ		18900	21	20.44	0	20.41	0
		18675	21	20.48	0	20.54	0
	January 1	19125	21	20.36	0	20.43	0
	36M	18900	21	20.36	0	20.48	0
		18675	21	20.49	0	20.52	0
		19125	21	20.39	0	20.49	0
	36L	18900	21	20.40	0	20.58	0
		18675	21	20.51	0	20.52	0
		19125	21	20.33	0	20.32	0
	75						
	75	18900	21	20.38	0	20.32	0
		18675	21	20.45	0	20.63	0
		19100	21	20.24	0	20.01	0
	1H	18900	21	20.03	0	20.11	0
		18700	21	20.37	0	20.35	0
		19100	21	20.65	0	20.00	0
	114						
	1M	18900	21	20.25	0	20.12	0
		18700	21	20.52	0	20.83	0
		19100	21	20.27	0	20.07	0
	1L	18900	21	20.11	0	20.07	0
		18700	21	20.28	0	20.07	0
		19100	21	20.32	0	20.30	0
20MHz	50H	18900	21	20.30	0	20.12	0
		18700	21	20.55	0	20.63	0
	L						
		19100	21	20.24	0	20.44	0
	50M	18900	21	20.31	0	20.36	0
		18700	21	20.45	0	20.56	0
		19100	21	20.34	0	20.54	0
	50L	18900	21	20.35	0	20.28	0
		18700	21	20.41	0	20.40	0
			21		0		0
	400	19100		20.26		20.22	
	100	18900	21	20.30	0	20.35	0
	1	18700	21	20.46	0	20.56	0



N		L1L	1900-FDD2 #		asured Pow	er (dBm) & M	PR
	1				SK		AM
BandWidth	RB No./Start	Channel	Tune-up	Measured	MPR	Measured	MPR
		19193	23	Power 21.24	0	Power 20.14	1
	1H	18900	23	21.24	0	20.14	1
		18607	23	21.64	0	20.25	1
		19193	23	21.60	0	20.17	1
	1M	18900	23	21.65	0	20.08	1
		18607	23	21.62	0	20.17	1
		19193	23	21.42	0	20.24	1
	1L	18900	23	21.08	0	20.12	1
		18607	23	21.25	0	20.21	1
1.4MHz	211	19193	23	21.35	0	20.36	1
1.410102	ЗН	18900 18607	23 23	21.48 21.49	0	20.02 20.28	1
		19193	23	21.43	0	20.20	1
	зм	18900	23	21.25	0	20.58	1
		18607	23	21.43	0	20.34	1
		19193	23	21.30	0	20.43	1
	3L	18900	23	21.30	0	20.40	1
		18607	23	21.48	0	20.30	1
		19193	23	20.21	1	19.30	2
	6	18900	23	20.24	1	19.41	2
		18607	23	20.42	1	19.07	2
		10105	00	01.15	0	20.00	4
	1H	19185	23 23	21.15 21.35	0	20.60 20.34	1
		18900 18615	23	21.35	0	20.34	1
		19185	23	21.33	0	20.73	1
	1M	18900	23	21.20	0	20.41	1
		18615	23	21.35	0	20.44	1
		19185	23	21.35	0	20.82	1
	1L	18900	23	21.06	0	20.02	1
		18615	23	21.56	0	20.19	1
		19185	23	20.12	1	19.31	2
3MHz	8H	18900	23	20.34	1	19.19	2
		18615	23	20.64	1	19.55	2
		19185	23	20.26	1	19.32	2
	8M	18900 18615	23 23	20.35 20.52	1	19.16 19.55	2
		19185	23	20.32	1	19.48	2
	8L	18900	23	20.28	1	19.23	2
		18615	23	20.44	1	19.52	2
		19185	23	20.29	1	19.26	2
	15	18900	23	20.34	1	19.08	2
		18615	23	20.40	1	19.36	2
		19175	23	21.06	0	20.80	1
	1H	18900	23	21.26	0	20.20	1
		18625 19175	23	21.62	0	20.90 20.38	1
	1M	19175	23 23	21.94 21.48	0	20.38	1
		18625	23	21.40	0	20.87	1
		19175	23	21.13	0	20.00	1
	1L	18900	23	21.08	0	20.25	1
		18625	23	21.54	0	20.01	1
		19175	23	20.20	1	19.14	2
5MHz	12H	18900	23	20.33	1	19.12	2
		18625	23	20.46	1	19.31	2
		19175	23	20.25	1	19.26	2
	12M	18900	23	20.34	1	19.34	2
		18625	23	20.59	1	19.55	2
	12L	19175 18900	23 23	20.17 20.29	1	19.23 19.35	2
	122	18900	23	20.29	1	19.35	2
		19175	23	20.47	1	19.46	2
	25	18900	23	20.25	1	19.34	2
	I I	18625	23	20.52	1	19.36	2

#### Table 11-7 LTE1900-FDD2 #2 Normal Power

# No. I18Z60544-SEM01 Page 31 of 186



		19150	23	21.27	0	20.01	1
	1H	18900	23	21.39	0	20.13	1
		18650	23	21.72	0	20.99	1
		19150	23	21.51	0	20.00	1
	1M	18900	23	21.51	0		1
	IIVI					20.48	
		18650	23	21.57	0	20.39	1
		19150	23	21.45	0	20.08	1
	1L	18900	23	21.50	0	20.27	1
		18650	23	21.80	0	20.35	1
		19150	23	20.18	1	19.21	2
10MHz	25H	18900	23	20.31	1	19.36	2
		18650	23	20.49	1	19.63	2
		19150	23	20.13	1	19.55	2
	25M	18900	23	20.31	1	19.50	2
	1	18650	23	20.60	1	19.47	2
		19150	23	20.11	1	19.43	2
	25L	18900	23	20.28	1	19.47	2
	ZOL						
	-	18650	23	20.58	1	19.40	2
	10002	19150	23	20.21	1	19.28	2
	50	18900	23	20.31	1	19.23	2
		18650	23	20.55	1	19.41	2
		19125	23	21.25	0	20.03	1
	1H	18900	23	21.19	0	20.04	1
		18675	23	21.88	0	20.95	1
		19125	23	21.47	0	20.74	1
	1M	18900	23	21.43	0	20.10	1
	1141	18675	23	21.43	0	20.99	1
	1L	19125	23	21.31	0	20.98	1
		18900	23	21.42	0	20.11	1
		18675	23	21.56	0	20.83	1
		19125	23	20.14	1	19.19	2
15MHz	36H	18900	23	20.24	1	19.21	2
		18675	23	20.51	1	19.48	2
		19125	23	20.13	1	19.22	2
	36M	18900	23	20.18	1	19.27	2
	1111000044	18675	23	20.41	1	19.39	2
		19125	23	20.16	1	19.14	2
	36L	18900	23	20.33	1	19.28	2
	302	18675	23	20.39	1	19.08	2
	75	19125	23	20.04	1	19.17	2
	75	18900	23	20.26	1	19.06	2
		18675	23	20.50	1	19.37	2
		19100	23	21.10	0	20.01	1
	1H	18900	23	21.03	0	20.02	1
		18700	23	21.30	0	20.32	1
		19100	23	21.69	0	20.04	1
	1M	18900	23	21.57	0	20.04	1
		18700	23	21.59	0	20.78	1
		19100	23	21.44	0	20.02	1
	1L	18900	23	21.07	0	20.03	1
		18700	23	21.02	0	20.05	1
		19100	23	20.02	1	19.02	2
20MHz	50H	18900	23	20.17	1	19.06	2
		18700	23	20.42	1	19.48	2
		19100	23	20.07	1	19.24	2
	50M	18900	23	20.17	1	19.22	2
		18700	23	20.46	1	19.40	2
		19100	23	20.11	1	19.07	2
	50L	18900	23	20.11	1	19.07	2
	302						
		18700	23	20.36	1	19.21	2
				00.77			
		19100	23	20.02	1	19.02	2
	100		23 23 23	20.02 20.15 20.37	1 1 1	19.02 19.23 19.27	2 2 2



# No. I18Z60544-SEM01 Page 32 of 186

#### Table 11-8 LTE850-FDD5 #1

		LTE	850-FDD5 #	1			
						er (dBm) & M	
Pond\//idth		Channel	Tuno un		SK		2AM
BandWidth	RB No./Start	Channel	Tune-up	Measured Power	MPR	Measured Power	MPR
		20643	24.3	22.91	0	22.13	1
	1H	20525	24.3	23.07	0	21.88	1
		20407	24.3	22.84	0	21.90	1
		20643	24.3	23.11	0	22.20	1
	1M	20525	24.3	23.05	0	21.81	1
		20407 20643	24.3 24.3	23.03 23.00	0	21.77 22.18	1
	1L	20525	24.3	23.00	0	21.73	1
		20407	24.3	22.72	0	22.26	1
		20643	24.3	23.08	0	22.11	1
1.4MHz	ЗН	20525	24.3	23.05	0	22.25	1
		20407	24.3	22.91	0	22.24	1
		20643	24.3	23.11	0	22.26	1
	3М	20525 20407	24.3 24.3	23.25 22.97	0	21.84 21.73	1
		20407	24.3	22.97	0	22.31	1
	3L	20525	24.3	23.14	0	22.12	1
		20407	24.3	22.86	0	21.76	1
		20643	24.3	21.97	1	21.25	2
	6	20525	24.3	21.97	1	20.69	2
	-	20407	24.3	22.02	1	21.08	2
					6		
	1H	20635	24.3	22.82	0	22.02	1
	1M	20525 20415	24.3 24.3	23.16 23.02	0	21.84 21.96	1
		20415	24.3	22.95	0	21.30	1
		20525	24.3	23.39	0	21.95	1
		20415	24.3	23.18	0	22.07	1
		20635	24.3	22.93	0	22.01	1
	1L	20525	24.3	22.99	0	21.92	1
		20415	24.3	23.20	0	21.77	1
3MHz	011	20635	24.3	22.01	1	20.92	2
SIVINZ	8H	20525 20415	24.3 24.3	22.09 22.11	1	21.08 20.94	2
		20635	24.3	22.06	1	20.67	2
	8M	20525	24.3	22.02	1	21.06	2
		20415	24.3	22.01	1	20.66	2
		20635	24.3	22.03	1	20.75	2
	8L	20525	24.3	21.97	1	21.03	2
		20415	24.3	21.97	1	20.83	2
	15	20635	24.3	22.10	1	20.77	2
	15	20525 20415	24.3 24.3	22.01 21.99	1	20.90	2
		20110	2.110	2		2	-
	1 1	20625	24.3	22.70	0	21.79	1
	1H	20525	24.3	22.97	0	21.57	1
		20425	24.3	22.92	0	22.04	1
		20625	24.3	23.10	0	21.74	1
	1M	20525	24.3	23.39	0	21.46	1
		20425	24.3	23.08	0	22.30	1
	1L	20625	24.3 24.3	22.90 23.02	0	21.87 21.66	1
		20325	24.3	22.74	0	21.50	1
		20625	24.3	21.95	1	20.77	2
5MHz	12H	20525	24.3	22.06	1	20.74	2
		20425	24.3	21.97	1	20.85	2
	Constant of	20625	24.3	22.11	1	20.78	2
	12M	20525	24.3	22.10	1	20.97	2
		20425	24.3	22.03	1	20.92	2
	101	20625	24.3	22.00	1	20.84	2
	12L	20525 20425	24.3 24.3	22.09 21.96	1	20.77 20.76	2
		20425	24.3	21.96	1	20.76	2
	25	20525	24.3	22.08	1	20.93	2
		20425	24.3	21.99	1	21.06	2